

# DB4X313K

## Silicon epitaxial planar type

For small current rectification

### ■ Features

- Low forward voltage  $V_F$  and small reverse current  $I_R$
- Low terminal capacitance  $C_t$
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

### ■ Basic Part Number

Dual DB2J313 (Parallel)

### ■ Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Reverse voltage	$V_R$	30	V
Repetitive peak reverse voltage	$V_{RRM}$	30	V
Forward current (Average)	Single	200	mA
	Double *1	130	
Peak forward current	Single	300	mA
	Double *1	220	
Non-repetitive peak forward surge current *2	Single	1.0	A
	Double *1	0.7	
Junction temperature	$T_j$	125	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +125	$^\circ\text{C}$

Note) \*1: Value of each diode in double diodes used.

\*2: 50 Hz sine wave 1 cycle (Non-repetitive peak current)

### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

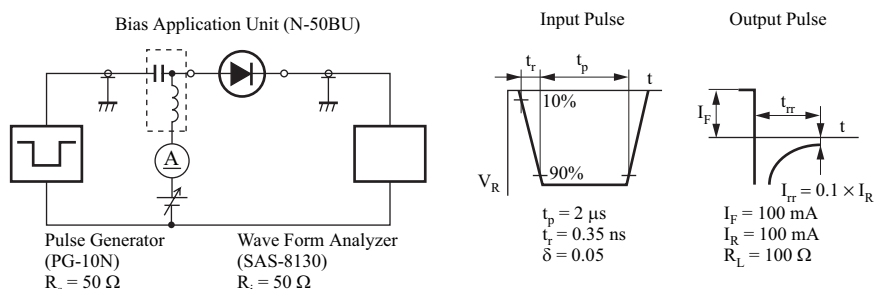
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Forward voltage	$V_F$	$I_F = 200 \text{ mA}$			0.55	V
Reverse current	$I_R$	$V_R = 30 \text{ V}$			50	$\mu\text{A}$
Terminal capacitance	$C_t$	$V_R = 10 \text{ V}, f = 1 \text{ MHz}$		3.8		pF
Reverse recovery time *	$t_{rr}$	$I_F = I_R = 10 \text{ mA}, I_{tr} = 0.1 \times I_R,$ $R_L = 100 \Omega$		1.5		ns

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

3. Absolute frequency of input and output is 1 GHz

4. \*:  $t_{rr}$  measurement circuit



### ■ Package

#### • Code

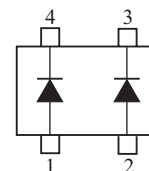
Mini4-G4-B

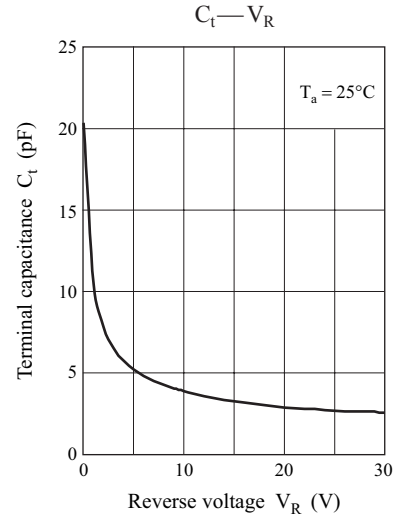
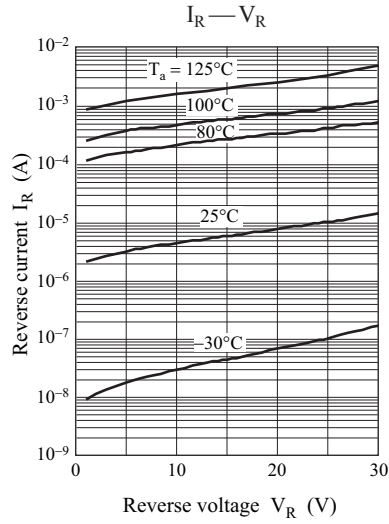
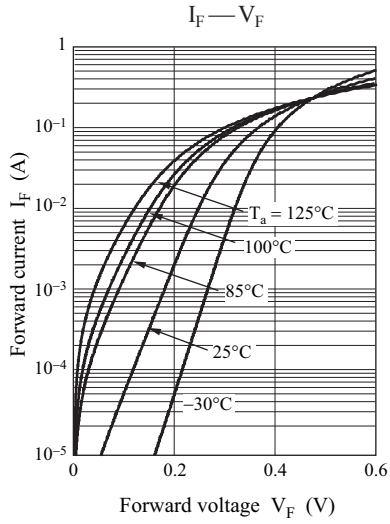
#### • Pin Name

1: Anode-1                      3: Cathode-2  
2: Anode-2                      4: Cathode-1

### ■ Marking Symbol: 4J

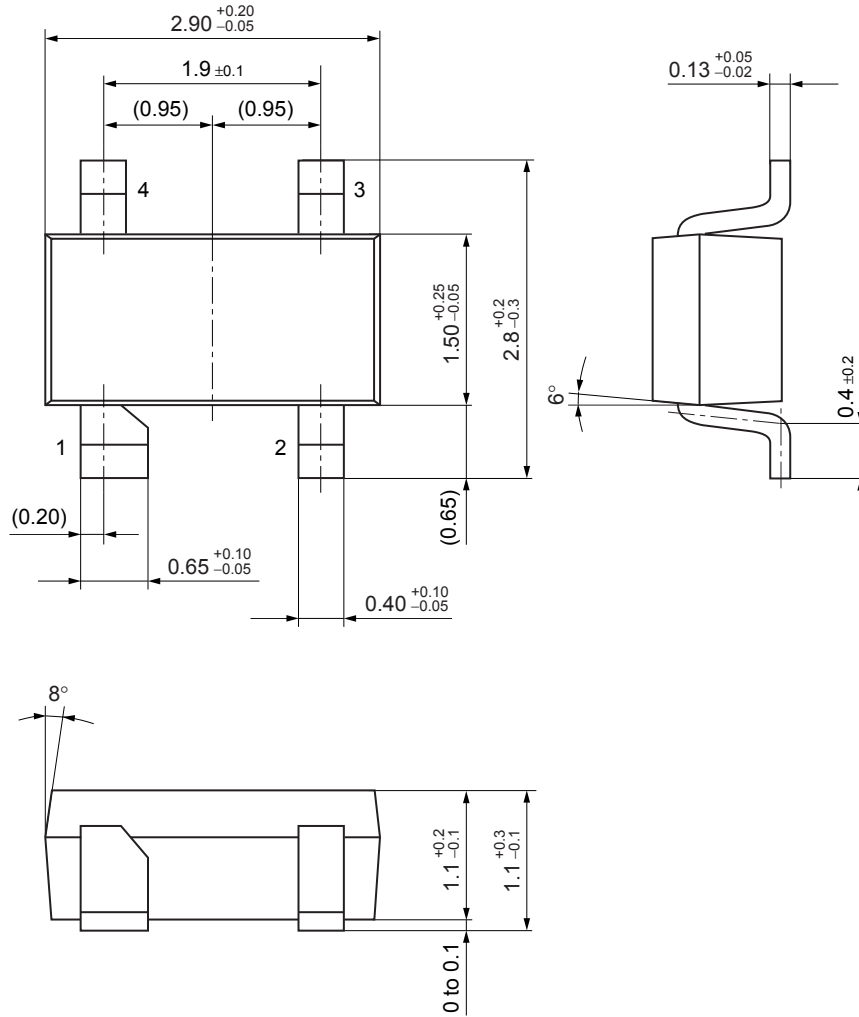
### ■ Internal Connection





Mini4-G4-B

Unit: mm



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